

# COMLINEAR® CLC1011, CLC2011, CLC4011

## Low Power, Low Cost, Rail-to-Rail I/O Amplifiers

#### **FEATURES**

- 136µA supply current
- 4.9MHz bandwidth
- Output swings to within 20mV of either rail
- Input voltage range exceeds the rail by >250mV
- 5.3V/µs slew rate
- 21nV/√Hz input voltage noise
- 16mA output current
- Fully specified at 2.7V and 5V supplies
- CLC1011: Pb-free SOT23-5, SC70-5, SOIC-8
- CLC2011: Pb-free SOIC-8, MSOP-8
- CLC4011: Pb-free SOIC-14. TSSOP-14

#### **APPLICATIONS**

- Portable/battery-powered applications
- PCMCIA, USB
- Mobile communications, cell phones, pagers
- ADC buffer
- Active filters
- Portable test instruments
- Notebooks and PDA's
- Signal conditioning
- Medical Equipment
- Portable medical instrumentatior

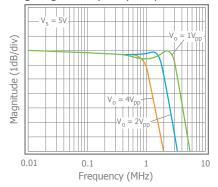
## **General Description**

The COMLINEAR CLC1011 (single), CLC2011 (dual), and CLC4011 (quad) are ultra-low cost, low power, voltage feedback amplifiers. At 5V, the CLCx011 family uses only  $160\mu\text{A}$  of supply current per amplifier and are designed to operate from a supply range of 2.5V to 5.5V ( $\pm 1.25$  to  $\pm 2.75$ ). The input voltage range exceeds the negative and positive rails.

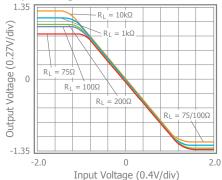
The CLCx011 family of amplifiers offer high bipolar performance at a low CMOS prices. They offer superior dynamic performance with 4.9MHz small signal bandwidths and 5.3V/µs slew rates. The combination of low power, high bandwidth, and rail-to-rail performance make the CLCx011 amplifiers well suited for battery-powered communication/computing systems

## Typical Performance Examples

Large Signal Frequency Response



Output Swing vs. Load

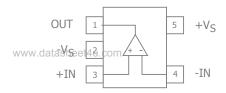


## **Ordering Information**

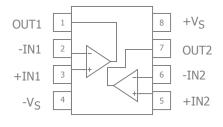
Part Number	Package	Pb-Free	RoHS Compliant	Operating Temperature Range	Packaging Method
CLC1011ISC5X*	SC70-5	Yes	Yes	-40°C to +85°C	Reel
CLC1011IST5X*	SOT23-5	Yes	Yes	-40°C to +85°C	Reel
CLC2011ISO8X*	SOIC-8	Yes	Yes	-40°C to +85°C	Reel
CLC2011IMP8X*	MSOP-8	Yes	Yes	-40°C to +85°C	Reel
CLC4011ISO14X*	SOIC-14	Yes	Yes	-40°C to +85°C	Reel
CLC4011ITP14X*	TSSOP-14	Yes	Yes	-40°C to +85°C	Reel

Moisture sensitivity level for all parts is MSL-1. \*Advance Information.

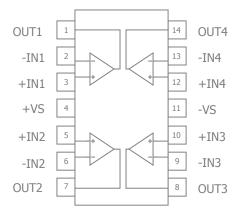
## **CLC1011 Pin Configuration**



## **CLC2011 Pin Configuration**



## **CLC4011 Pin Configuration**



## **CLC1011 Pin Assignments**

Pin No.	Pin Name	Description
1	OUT	Output
2	-V <sub>S</sub>	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	+V <sub>S</sub>	Positive supply

## **CLC2011 Pin Configuration**

Pin No.	Pin Name	Description	
1	OUT1	Output, channel 1	
2	-IN1	Negative input, channel 1	
3	+IN1	Positive input, channel 1	
4	-V <sub>S</sub>	Negative supply	
5	+IN2	Positive input, channel 2	
6	-IN2	Negative input, channel 2	
7	OUT2	Output, channel 2	
8	+V <sub>S</sub>	Positive supply	

## **CLC4011 Pin Configuration**

Pin No.	Pin Name	Description	
1	OUT1	Output, channel 1	
2	-IN1	Negative input, channel 1	
3	+IN1	Positive input, channel 1	
4	+Vs	Positive supply	
5	+IN2	Positive input, channel 2	
6	-IN2	Negative input, channel 2	
7	OUT2	Output, channel 2	
8	OUT3	Output, channel 3	
9	-IN3	Negative input, channel 3	
10	+IN3	Positive input, channel 3	
11	-V <sub>S</sub>	Negative supply	
12	+IN4	Positive input, channel 4	
13	-IN4	Negative input, channel 4	
14	OUT4	Output, channel 4	

## **Absolute Maximum Ratings**

The safety of the device is not guaranteed when it is operated above the "Absolute Maximum Ratings". The device should not be operated at these "absolute" limits. Adhere to the "Recommended Operating Conditions" for proper device function. The information contained in the Electrical Characteristics tables and Typical Performance plots reflect the operating conditions noted on the tables and plots.

Parameter 4u.com	Min	Max	Unit
Supply Voltage	0	6	V
Input Voltage Range	-V <sub>s</sub> -0.5V	+V <sub>S</sub> +0.5V	V
Continuous Output Current	-30	30	mA

## **Reliability Information**

Parameter	Min	Тур	Max	Unit
Junction Temperature			175	°C
Storage Temperature Range	-65		150	°C
Lead Temperature (Soldering, 10s)			260	°C
Package Thermal Resistance				
5-Lead SC70		TBD		°C/W
5-Lead SOT23		TBD		°C/W
8-Lead SOIC		TBD		°C/W
8-Lead MSOP		TBD		°C/W
14-Lead SOIC		TBD		°C/W
14-Lead TSSOP		TBD		°C/W

Notes:

Package thermal resistance ( $\theta_{\mbox{\scriptsize JA}}$ ), JDEC standard, multi-layer test boards, still air.

#### **ESD Protection**

Product	SC70-5	SOT23-5	SOIC-8	MSOP-8	SOIC-14	TSSOP-14
Human Body Model (HBM)	TBD	TBD	TBD	TBD	TBD	TBD
Charged Device Model (CDM)	TBD	TBD	TBD	TBD	TBD	TBD

## **Recommended Operating Conditions**

Parameter	Min	Тур	Max	Unit
Operating Temperature Range	-40		+85	°C
Supply Voltage Range	2.5		5.5	V

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## Electrical Characteristics at +2.7V

 $T_A=25^{\circ}\text{C},\,V_S=+2.7\text{V},\,R_f=R_g$  =5k $\Omega,\,R_L=10\text{k}\Omega$  to  $V_S/2,\,G=2;$  unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency D	omain Response					
UGBW <sub>SS</sub>	Unity Gain -3dB Bandwidth	$G = +1$ , $V_{OUT} = 0.02V_{pp}$		4.9		MHz
vv <b>BW</b> stashee	4u. <b>€3dB</b> Bandwidth	$G = +2$ , $V_{OUT} = 0.2V_{pp}$		3.7		MHz
BW <sub>LS</sub>	Large Signal Bandwidth	$G = +2$ , $V_{OUT} = 2V_{pp}$		1.4		MHz
GBWP	Gain Bandwdith Product	$G = +11, V_{OUT} = 0.2V_{pp}$		2.2		MHz
Time Domai	n Response					
t <sub>R</sub> , t <sub>F</sub>	Rise and Fall Time	V <sub>OUT</sub> = 1V step; (10% to 90%)		163		ns
OS	Overshoot	V <sub>OUT</sub> = 1V step		<1		%
SR	Slew Rate	1V step		5.3		V/µs
Distortion/N	pise Response					
HD2	2nd Harmonic Distortion	V <sub>OUT</sub> = 1V <sub>pp</sub> , 10kHz		-72		dBc
HD3	3rd Harmonic Distortion	V <sub>OUT</sub> = 1V <sub>pp</sub> , 10kHz		-72		dBc
THD	Total Harmonic Distortion	V <sub>OUT</sub> = 1V <sub>pp</sub> , 10kHz		0.03		%
e <sub>n</sub>	Input Voltage Noise	> 10kHz		21		nV/√Hz
DC Performa	nce					
V <sub>IO</sub>	Input Offset Voltage (1)		-6	0.5	6	mV
dV <sub>IO</sub>	Average Drift			5		μV/°C
I <sub>b</sub>	Input Bias Current (1)			90	420	nA
dI <sub>b</sub>	Average Drift			32		pA/°C
PSRR	Power Supply Rejection Ratio (1)	DC	55	83		dB
A <sub>OL</sub>	Open-Loop Gain	$V_{OUT} = V_S / 2$		90		dB
I <sub>S</sub>	Supply Current (1)	per channel		136	190	μΑ
Input Charac	teristics					
R <sub>IN</sub>	Input Resistance	Non-inverting		12		МΩ
C <sub>IN</sub>	Input Capacitance			2		pF
CMIR	Common Mode Input Range			-0.25 to 2.95		V
CMRR	Common Mode Rejection Ratio (1)	DC	55	81		dB
Output Char	acteristics					'
		$R_L = 10k\Omega$ to $V_S/2$ <sup>(1)</sup>	0.06 to 2.64	0.02 to 2.68		V
V <sub>OUT</sub>	Output Voltage Swing	$R_L = 1k\Omega$ to $V_S/2$		0.05 to 2.63		V
		$R_L = 200\Omega$ to $V_S/2$		0.11 to 2.52		V
I <sub>OUT</sub>	Output Current			±16		mA

#### Notes:

1. 100% tested at 25°C

## Electrical Characteristics at +5V

 $T_A=25^{o}C,\,V_S=+5V,\,R_f=R_g=5k\Omega,\,R_L=10k\Omega$  to  $V_S/2,\,G=2;$  unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency D	omain Response	<u> </u>				
UGBW <sub>SS</sub>	Unity Gain -3dB Bandwidth	$G = +1$ , $V_{OUT} = 0.02V_{pp}$		4.3		MHz
vv <b>BW</b> stasheet	4u. <b>€3dB</b> Bandwidth	$G = +2$ , $V_{OUT} = 0.2V_{pp}$		3.0		MHz
BW <sub>LS</sub>	Large Signal Bandwidth	$G = +2$ , $V_{OUT} = 2V_{pp}$		2.3		MHz
GBWP	Gain Bandwdith Product	$G = +11, V_{OUT} = 0.2V_{pp}$		2.0		MHz
Time Domair	n Response					
t <sub>R</sub> , t <sub>F</sub>	Rise and Fall Time	V <sub>OUT</sub> = 1V step; (10% to 90%)		110		ns
OS	Overshoot	V <sub>OUT</sub> = 1V step		<1		%
SR	Slew Rate	1V step		9		V/µs
Distortion/No	pise Response					
HD2	2nd Harmonic Distortion	V <sub>OUT</sub> = 1V <sub>pp</sub> , 10kHz		-73		dBc
HD3	3rd Harmonic Distortion	V <sub>OUT</sub> = 1V <sub>pp</sub> , 10kHz		-75		dBc
THD	Total Harmonic Distortion	V <sub>OUT</sub> = 1V <sub>pp</sub> , 10kHz		0.03		%
e <sub>n</sub>	Input Voltage Noise	> 10kHz		22		nV/√Hz
DC Performa	nce	,				
V <sub>IO</sub>	Input Offset Voltage (1)		-8	1.5	8	mV
dV <sub>IO</sub>	Average Drift			15		μV/°C
I <sub>b</sub>	Input Bias Current (1)			90	450	nA
dI <sub>b</sub>	Average Drift			40		pA/°C
PSRR	Power Supply Rejection Ratio (1)	DC	40	60		dB
A <sub>OL</sub>	Open-Loop Gain	$V_{OUT} = V_S / 2$		80		dB
I <sub>S</sub>	Supply Current (1)	per channel		160	235	μΑ
Input Charac	teristics					
R <sub>IN</sub>	Input Resistance	Non-inverting		12		MΩ
C <sub>IN</sub>	Input Capacitance			2		pF
CMIR	Common Mode Input Range			-0.25 to 5.25		V
CMRR	Common Mode Rejection Ratio (1)	DC	58	85		dB
Output Chara	acteristics					
		$R_L = 10k\Omega$ to $V_S/2$ <sup>(1)</sup>	0.08 to 4.92	0.04 to 4.96		V
V <sub>OUT</sub>	Output Voltage Swing	$R_L = 1k\Omega$ to $V_S/2$		0.07 to 4.9		V
		$R_L = 200\Omega$ to $V_S/2$		0.14 to 4.67		V
I <sub>OUT</sub>	Output Current			±30		mA

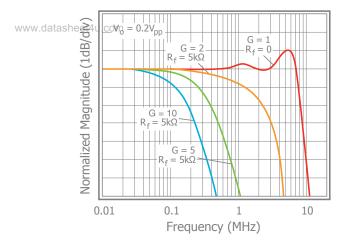
#### Notes:

1. 100% tested at 25°C

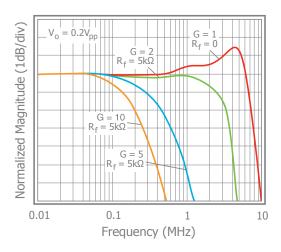
## Typical Performance Characteristics

 $T_A = 25$ °C,  $V_S = +2.7V$ ,  $R_f = R_q = 5k\Omega$ ,  $R_L = 10k\Omega$  to  $V_S/2$ , G = 2; unless otherwise noted.

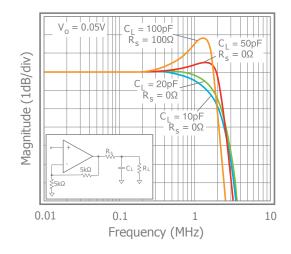
Non-Inverting Frequency Response at  $V_S = 5V$ 



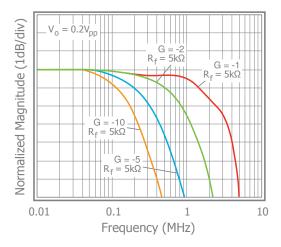
Non-Inverting Frequency Response



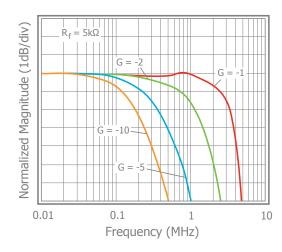
Frequency Response vs. CL



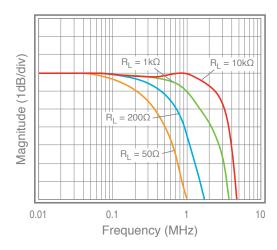
#### Inverting Frequency Response at $V_S = 5V$



**Inverting Frequency Response** 



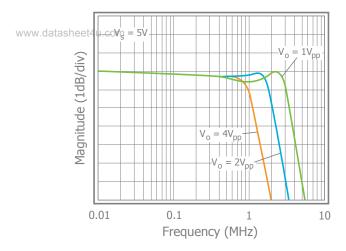
Frequency Response vs. R<sub>L</sub>



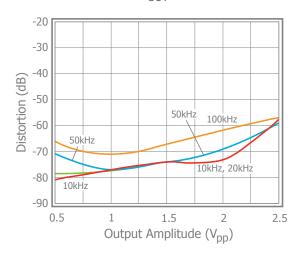
## **Typical Performance Characteristics**

 $T_A=25$ °C,  $V_S=+2.7$ V,  $R_f=R_q=5k\Omega$ ,  $R_L=10k\Omega$  to  $V_S/2$ , G=2; unless otherwise noted.

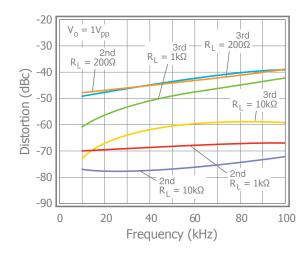
### Frequency Response vs. V<sub>OUT</sub>



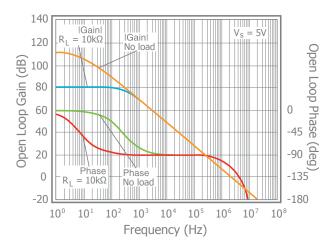
#### 2nd Harmonic Distortion vs. V<sub>OUT</sub>



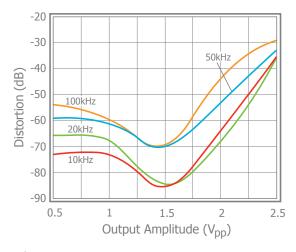
2nd & 3rd Harmonic Distortion



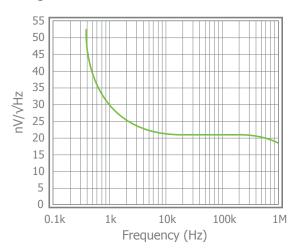
#### Open Loop Gain & Phase vs. Frequency



3rd Harmonic Distortion vs. V<sub>OUT</sub>



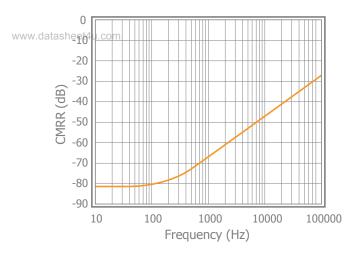
Input Voltage Noise



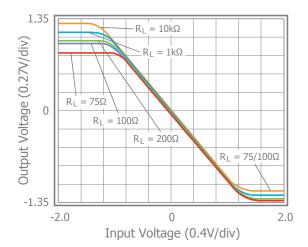
## Typical Performance Characteristics - Continued

 $T_A=25$  °C,  $V_S=\pm5V,$   $R_f=R_g$  =150  $\Omega,$   $R_L=150 \Omega,$  G=2; unless otherwise noted.

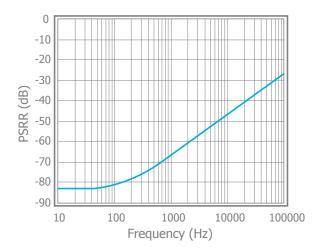
#### **CMRR**



#### Output Swing vs. Load



#### **PSRR**



Pulse Response vs. Common Mode Voltage

#### **Application Information**

#### **General Description**

The CLCx011 family of amplifiers are single supply, general purpose, voltage-feedback amplifiers. They are fabricated on a complimentary bipolar process, feature a rail-to-rail in-

#### **Basic Operation**

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations.

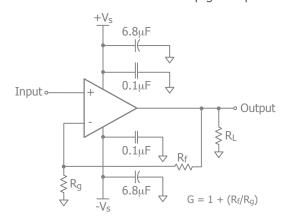


Figure 1. Typical Non-Inverting Gain Circuit

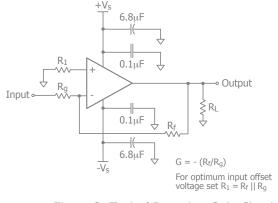


Figure 2. Typical Inverting Gain Circuit

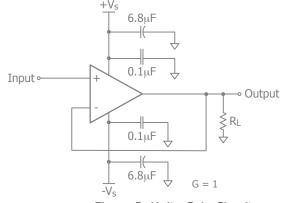


Figure 3. Unity Gain Circuit

#### **Power Dissipation**

Power dissipation should not be a factor when operating under the stated 10k ohm load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond it's intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Theta<sub>JA</sub>  $(\Theta_{1A})$  is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} + (\Theta_{JA} \times P_{D})$$

Where T<sub>Ambient</sub> is the temperature of the working environment.

In order to determine  $P_D$ , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{supply} - P_{load}$$

Supply power is calculated by the standard power equation.

$$P_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$$

$$V_{\text{supply}} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{LOAD})_{RMS^2})/Rload_{eff}$$

The effective load resistor (Rload<sub>eff</sub>) will need to include the effect of the feedback network. For instance,

Rload<sub>eff</sub> in figure 3 would be calculated as:

$$R_L \mid\mid (R_f + R_q)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here,  $P_D$  can be found from

$$P_D = P_{Quiescent} + P_{Dynamic} - P_{Load}$$

Quiescent power can be derived from the specified  $I_S$  values along with known supply voltage,  $V_{Supply}$ . Load power can be calculated as above with the desired signal amplitudes using:

$$(V_{LOAD})_{RMS} = V_{PEAK} / \sqrt{2}$$

$$(I_{LOAD})_{RMS} = (V_{LOAD})_{RMS} / Rload_{eff}$$

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The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{DYNAMIC} = (V_{S+} - V_{LOAD})_{RMS} \times (I_{LOAD})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or  $V_{\text{supply}}/2$ .

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Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

Figure 4. Maximum Power Derating

#### Input Common Mode Voltage

The common mode input range extends to 250mV below ground and to 250mV above Vs, in single supply operation. Exceeding these values will not cause phase reversal. However, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices will begin to conduct. The output will stay at the rail during this overdrive condition. If the absolute maximum input voltage (700mV beyond either rail) is exceeded, externally limit the input current to  $\pm 5$ mA as shown in Figure 5.

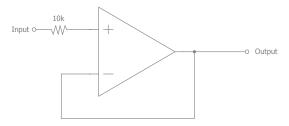


Figure 5. Circuit for Input Current Protection

#### **Driving Capacitive Loads**

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response,

and possible unstable behavior. Use a series resistance,  $R_S$ , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 6.

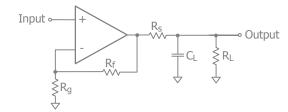


Figure 6. Addition of R<sub>S</sub> for Driving Capacitive Loads

Table 1 provides the recommended  $R_S$  for various capacitive loads. The recommended  $R_S$  values result in approximately <1dB peaking in the frequency response. The Frequency Response vs.  $C_L$  plot, on page 6, illustrates the response of the CLCx011.

C <sub>L</sub> (pF)	R <sub>S</sub> (Ω)	-3dB BW (kHz)
10pF	0	2.2
20pF	0	2.4
50pF	0	2.5
100pF	100	2

Table 1: Recommended R<sub>S</sub> vs. C<sub>L</sub>

For a given load capacitance, adjust  $R_S$  to optimize the tradeoff between settling time and bandwidth. In general, reducing  $R_S$  will increase bandwidth at the expense of additional overshoot and ringing.

#### Overdrive Recovery

An overdrive condition is defined as the point when either one of the inputs or the output exceed their specified voltage range. Overdrive recovery is the time needed for the amplifier to return to its normal or linear operating point. The recovery time varies, based on whether the input or output is overdriven and by how much the range is exceeded. The CLCx011 will typically recover in less than 50ns from an overdrive condition. Figure 7 shows the CLC1011 in an overdriven condition.

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Figure 7. Overdrive Recovery

#### **Layout Considerations**

General layout and supply bypassing play major roles in high frequency performance. CADEKA has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include  $6.8\mu F$  and  $0.1\mu F$  ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

#### **Evaluation Board Information**

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board	Products
CEB011	CLC1011 in SC70
CEB002	CLC1011 in SOT23
CEB006	CLC2011 in SOIC
CEB010	CLC2011 in MSOP
CEB018	CLC4011 in SOIC
CEB017	CLC4011 in TSSOP

#### **Evaluation Board Schematics**

Evaluation board schematics and layouts are shown in Figures 8-14. These evaluation boards are built for dual- supply operation. Follow these steps to use the board in a single-supply application:

- 1. Short -Vs to ground.
- 2. Use C3 and C4, if the  $-V_S$  pin of the amplifier is not directly connected to the ground plane.

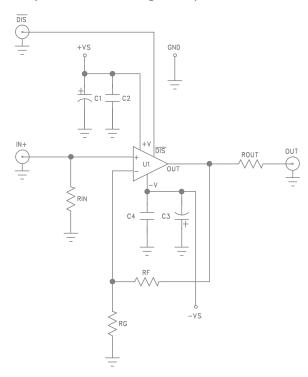


Figure 8. CEB002 Schematic

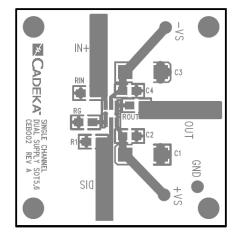


Figure 9. CEB002 Top View

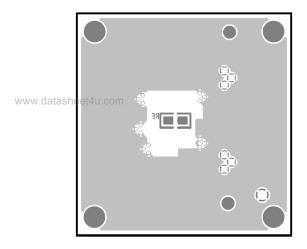


Figure 10. CEB002 Bottom View

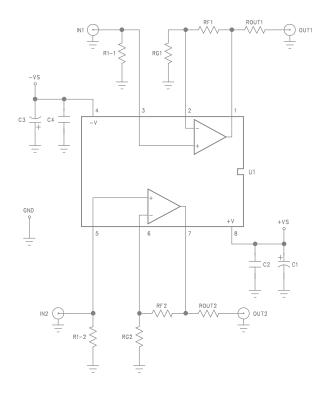


Figure 11. CEB006 Schematic

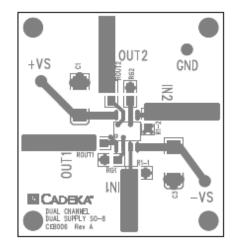


Figure 12. CEB006 Top View

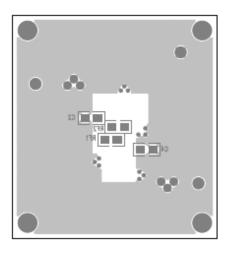


Figure 13. CEB006 Bottom View

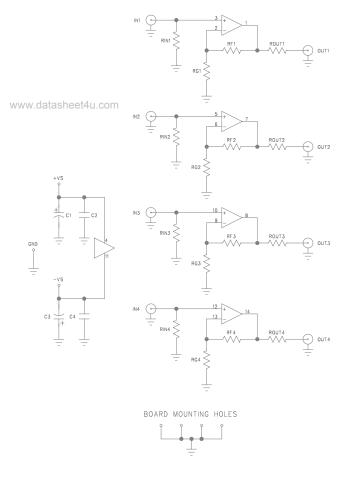


Figure 14. CEB018 Schematic

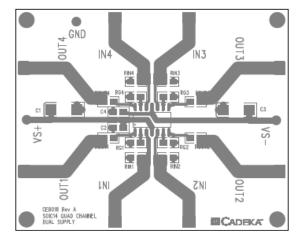


Figure 15. CEB018 Top View

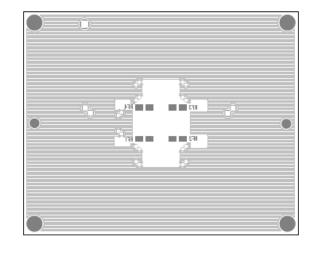
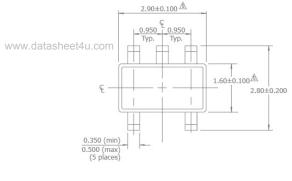


Figure 16. CEB018 Bottom View

#### **Mechanical Dimensions**

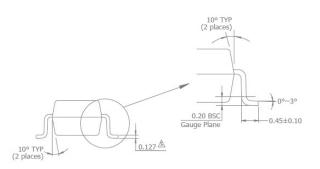
#### SOT23-5 Package



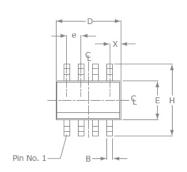
# 10° TYP (2 places) 1.15±0.150 Seating Plane (2 places) 0.05 (min) 0.15 (max)

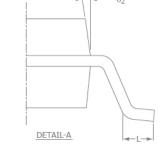
#### NOTES:

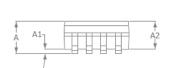
- 1. Dimensions and tolerances are as per ANSI Y14.5M-1982.
- 2. Package surface to be matte finish VDI 11 $\sim$ 13.
- 3. Die is facing up for mold. Die is facing down for trim/form, ie. reverse trim/form.
- 4. The footlength measuring is based on the guage plane method.
- ▲ Dimension are exclusive of mold flash and gate burr.
- ≜ Dimension are exclusive of solder plating.

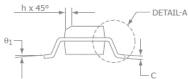


#### SOIC-8 Package









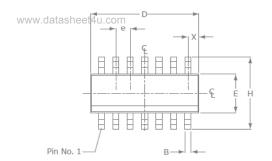
SOIC-8		
SYMBOL	MIN	MAX
A1	0.10	0.25
В	0.36	0.48
С	0.19	0.25
D	4.80	4.98
Е	3.81	3.99
е	1.27 BSC	
Н	5.80	6.20
h	0.25	0.5
L	0.41	1.27
А	1.37	1.73
θ1	00	80
Х	0.55 ref	
θ2	7° BSC	

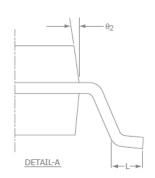
#### NOTE

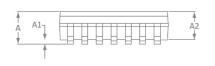
- 1. All dimensions are in millimeters.
- 2. Lead coplanarity should be 0 to 0.1mm (0.004") max.
- 3. Package surface finishing: VDI 24~27
- 4. All dimension excluding mold flashes.
- 5. The lead width, B to be determined at 0.1905mm from the lead tip.

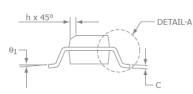
## Mechanical Dimensions continued

SOIC-14 Package









SOIC-14			
SYMBOL	MIN	MAX	
A1	0.10	0.25	
В	0.36	0.48	
С	0.19	0.25	
D	8.56	8.74	
E	3.84	3.99	
е	1.27 BSC		
Н	5.80	6.20	
h	0.25	0.5	
L	0.41	1.27	
A	1.37	1.73	
$\theta_1$	00	80	
X	0.51 ref		
θ2	7º BSC		

#### NOTE:

- 1. All dimensions are in millimeters.
  2. Lead coplanarity should be 0 to 0.1mm (0.004") max
- 3. Package surface finishing: VDI 24~27
- 4. All dimension excluding mold flashes.
- 5. The lead width, B to be determined at 0.1905mm from the lead tip.

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